www.vishay.com

Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

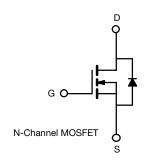


PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 V$	0.0035			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0040			
I _D (A)	120			
Configuration	Single			
Package	TO-220			

FEATURES

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- AEC-Q101 qualified d
- 100 % $\rm R_g$ and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unles	s otherwise notec	I)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current	T _C = 25 °C ^a		120		
	T _C = 125 °C	I _D	102		
Continuous source current (diode conduction) ^a		I _S	120	А	
Pulsed drain current ^b		I _{DM}	480		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	100		
Single pulse avalanche energy		E _{AS}	500	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D_	250	W	
	T _C = 125 °C	P _D	83	vv	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W		
unction-to-case (drain)		R _{thJC}	0.6	0/10		

- Notes
- a. Package limited.
- b. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.

SQP120N06-3m5L



Vishay Siliconix

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	•							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		60	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		2.0	2.5		
Gate-source leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1		
	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 60 V, T _J = 175 °C	-	-	900		
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	120	-	-	Α	
Drain-source on-state resistance ^a		V _{GS} = 10 V	I _D = 30 A	-	0.0025	0.0035	Ω	
		V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0064		
	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 30 A, T _J = 175 °C	-	-	0.0080		
		$V_{GS} = 4.5 V$	I _D = 20 A	-	0.0028	0.0040		
Forward transconductance b	g _{fs}	V _{DS} = 15 V, I _D = 30 A		-	190	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	11 755	14 700	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$ V_{DS}		-	1112	1400		
Reverse transfer capacitance	C _{rss}			-	481	605		
Total gate charge ^c	Qg		V _{DS} = 30 V, I _D = 110 A	-	220	330	nC	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$		-	35	-		
Gate-drain charge ^c	Q _{gd}			-	35	-		
Gate resistance	Rg	f = 1 MHz		0.6	1.3	2	Ω	
Turn-on delay time ^c	t _{d(on)}	$V_{DD}=30~V,~R_L=0.27~\Omega$ $I_D\cong110~A,~V_{GEN}=10~V,~R_g=2.5~\Omega$		-	19	29	- ns	
Rise time ^c	t _r			-	23	35		
Turn-off delay time ^c	t _{d(off)}			-	83	125		
Fall time ^c	t _f			-	35	53		
Source-Drain Diode Ratings and Char	racteristics ^b							
Pulsed current ^a	I _{SM}			-	-	480	А	
		I _F = 50 A, V _{GS} = 0				1.5	V	

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

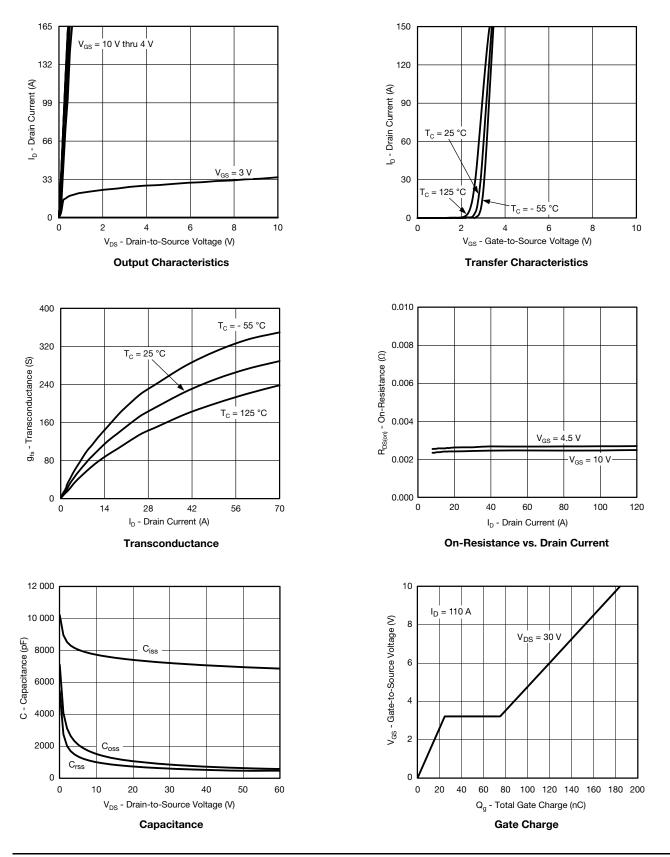
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SQP120N06-3m5L

Vishay Siliconix

TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



S16-2643-Rev. A, 26-Dec-16

3

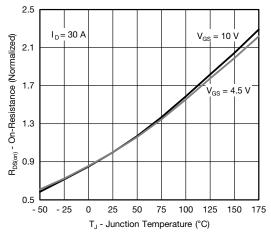
Document Number: 62854

For technical questions, contact: <u>automostechsupport@vishay.com</u>
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT
ARE SUBJECT TO SPECIFI
Downloaded From Oneyac.com
W.vishay.com/doc?91000

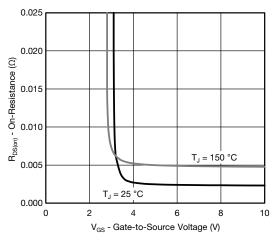


Vishay Siliconix

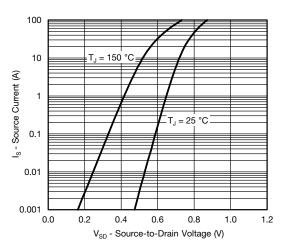
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



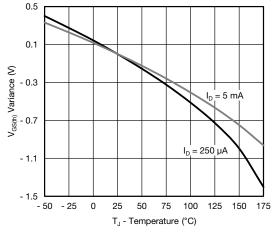
On-Resistance vs. Junction Temperature



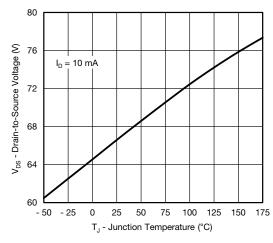
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage



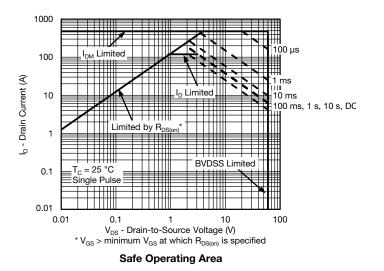
Drain Source Breakdown vs. Junction Temperature

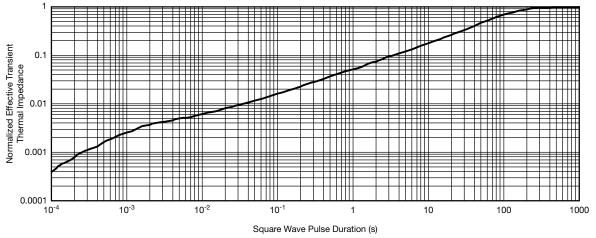


SQP120N06-3m5L

Vishay Siliconix

THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



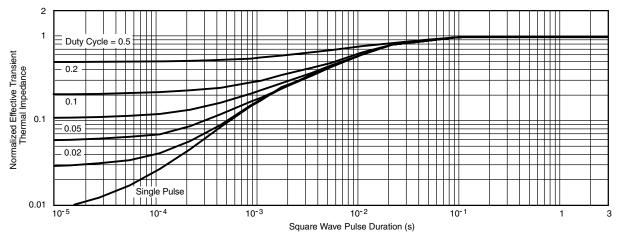


Normalized Thermal Transient Impedance, Junction-to-Ambient



Vishay Siliconix

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62854.



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.



单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)